

# BTW69-1200N

## 50 A – 1200 V non insulated SCR thyristor

## Datasheet - production data



Available in non insulated TOP3 high power package, the BTW69-1200N is suitable for applications where power switching and power dissipation are critical, such as by-pass switch, controlled AC rectifier bridge, in solid state relay, battery charger, uninterruptible power supply, welding equipment and motor driver applications.

Based on a clip assembly technology, the BTW69-1200N offers a superior performance in surge current handling and thermal cooling capabilities.

#### Table 1. Device summary

Symbol	Value
I <sub>T(RMS)</sub>	50 A
V <sub>DRM</sub> /V <sub>RRM</sub>	1200 V
I <sub>GT</sub>	50 mA

### Features

On-state rms current: 50 A

**TOP3 non insulated** 

- Blocking voltage: 1200 V
- Gate current: 50 mA

## Applications

- Solid state relay
- Battery charging system
- Uninterruptible power supply
- Variable speed motor drive
- Industrial welding systems
- By pass AC switch

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# 1 Characteristics

Symbol	Parameter			Value	Unit
I <sub>T(RMS)</sub>	On-state current rms (180° conduction and	gle)	T <sub>c</sub> = 102 °C	50	А
IT <sub>(AV)</sub>	Average on-state current (180° conduction	n angle)	T <sub>c</sub> = 102 °C	31	А
	Non repetitive surge peak on-state $t_p = 8.3 \text{ ms}$		T _ 25 °C	763	^
ITSM current		t <sub>p</sub> = 10 ms	T <sub>j</sub> = 25 °C	700	A
l <sup>2</sup> t	I <sup>2</sup> t Value	2450	A <sup>2</sup> s		
dl/dt	Critical rate of rise of on-state current Gate supply: $I_G = 100$ mA, $dI_G/dt = 1$ A/µs			100	A/µs
$I_{GM}$	Peak gate current $t_p = 20 \ \mu s$ $T_j = 125 \ ^\circ C$		8	А	
P <sub>G(AV)</sub>	Average gate power dissipation	1	W		
T <sub>stg</sub>	Storage junction temperature range			- 40 to + 150	°C
Тj	Operating junction temperature range			- 40 to + 125	0
$V_{GM}$	Maximum peak reverse gate voltage			5	V

Table 2. Absolute maximum	n ratings (limiting values)	
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## Table 3. Electrical characteristics ( $T_i = 25$ °C, unless otherwise specified)

Symbol	Test conditions	Value	Unit		
1			MIN.	8	~^^
I <sub>GT</sub>	$V_D$ = 12 V, $R_L$ = 33 $\Omega$		MAX.	50	mA
V <sub>GT</sub>			MAX.	1.3	V
V <sub>GD</sub>	$V_D = V_{DRM,} R_L = 3.3 \text{ k}\Omega$	T <sub>j</sub> = 125 °C	MIN.	0.2	V
I <sub>Н</sub>	I <sub>T</sub> = 500 mA, gate open		MAX.	100	mA
١ <sub>L</sub>	$I_{G} = 1.2 \times I_{GT}$		TYP.	125	mA
t <sub>gt</sub>	$I_T = 50 \text{ A}, \text{ V}_D = \text{V}_{DRM}, \text{ I}_G = 200 \text{ mA}, \text{ dI}_G/\text{dt} = 0.2 \text{ A}/\mu\text{s}$		TYP.	2	μs
dV/dt	$V_{D} = 67\% V_{DRM}$ , gate open	T <sub>j</sub> = 125 °C	MIN.	1000	V/µs
t <sub>q</sub>	$V_D = 800 \text{ V}, I_{TM} = 50 \text{ A}, V_R = 75 \text{ V},$ $t_p = 100  \mu\text{s},  dI_{TM}/\text{d} t = 30  A/\mu\text{s},$ $dV_D/\text{d} t = 20  V/\mu\text{s}$	T <sub>j</sub> = 125 °C	TYP.	100	μs
V <sub>TM</sub>	I <sub>TM</sub> = 100 A, t <sub>p</sub> = 380 μs	T <sub>j</sub> = 25 °C	MAX.	1.6	V
V <sub>t0</sub>	Threshold voltage	T <sub>j</sub> = 125 °C	MAX.	0.9	V
R <sub>D</sub>	Dynamic resistance	T <sub>j</sub> = 125 °C	MAX.	8.5	mΩ
I <sub>DRM</sub>	$V_{D} = V_{DRM}$	T <sub>j</sub> = 25 °C	MAX.	10	μA
I <sub>RRM</sub>	$V_{R} = V_{RRM}$	T <sub>j</sub> = 125 °C	ινι <i>τ</i> ιΛ.	5	mA



Symbol	Parameter	Value	Unit	
R <sub>th(j-c)</sub>	Junction to case (DC, typ.)	0.45	°C/W	
R <sub>th(j-a)</sub>	Junction to ambient (DC)	50	°C/W	

### Table 4. Thermal resistance

# Figure 1. Maximum average power dissipation versus average on-state current

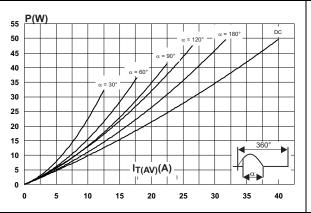


Figure 3. Average and DC on-state current versus case temperature

# Figure 2. Correlation between maximum average power dissipation and maximum allowable temperatures

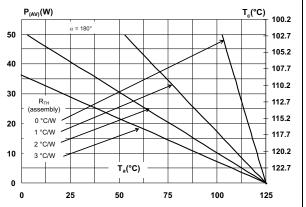


Figure 4. Average and DC on-state current versus ambient temperature

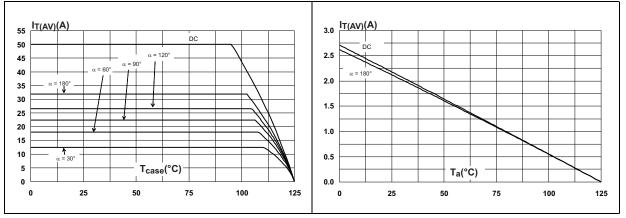




Figure 5. Relative variation of thermal impedance versus pulse duration

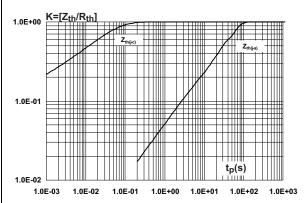


Figure 7. Relative variation of holding, and latching currents versus junction temperature (typical values)

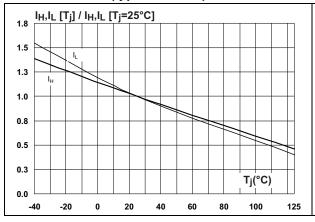


Figure 9. Non repetitive surge peak on-state current and corresponding value of I<sup>2</sup>t versus sinusoidal pulse

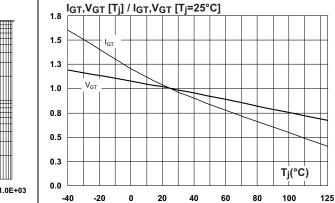
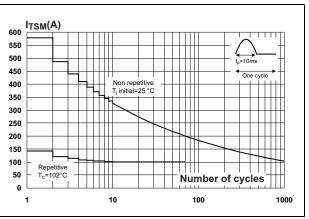
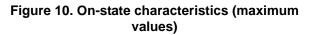


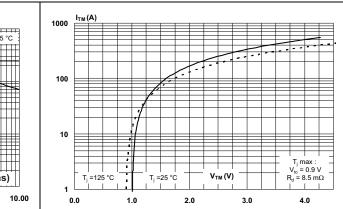
Figure 8. Surge peak on-state current versus number of cycles

Figure 6. Relative variation of gate trigger

current and gate trigger voltage versus junction temperature (typical value)







ITSM(A), I<sup>2</sup>t (A<sup>2</sup>s) dl/dt limitation: 100 A/µs T, initial=25 °C ++++ l²t width with pulse < 10 ms t<sub>p</sub>(ms) 0.10 1.00



10000

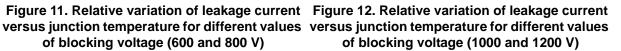
1000

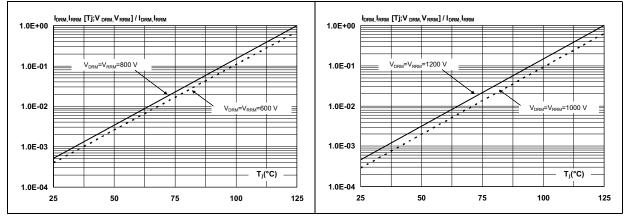
100

10

0.01

# of blocking voltage (600 and 800 V)







## 2 Package information

- Epoxy meets UL94,V0
- Lead-free packages
- Cooling method: by conduction (C)
- Recommended torque value: 0.9 to 1.2 N·m

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: *www.st.com.* ECOPACK<sup>®</sup> is an ST trademark.

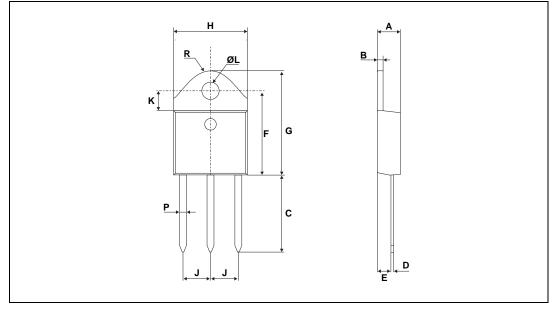


Figure 13. TOP3 dimension definitions

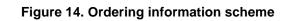


Dimensions					
Ref.	Millim	eters	Inches		
	Min.	Max.	Min.	Max.	
А	4.4	4.6	0.173	0.181	
В	1.45	1.55	0.057	0.061	
С	14.35	15.60	0.565	0.614	
D	0.5	0.7	0.020	0.028	
E	2.7	2.9	0.106	0.114	
F	15.8	16.5	0.622	0.650	
G	20.4	21.1	0.815	0.831	
Н	15.1	15.5	0.594	0.610	
J	5.4	5.65	0.213	0.222	
K	3.4	3.65	0.134	0.144	
ØL	4.08	4.17	0.161	0.164	
Р	1.20	1.40	0.047	0.055	
R	4.60	typ.	0.18	l typ.	

Table 5. TOP3 dimension values



## **3** Ordering information



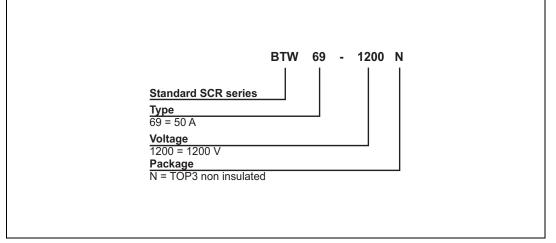


Table 6. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
BTW69-1200N	BTW691200N	TOP3	4.55 g	30	Tube

# 4 Revision history

Table 7. Document revision history	Table 7	. Document	revision	history
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Date	Revision	Changes
14-Jun-2013	1	Initial release.



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